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Roll No.:....

# 333353(33)

## B. E. (Third Semester) Examination, April-May 2021

(New Scheme)

(IT Engg. Branch)

### **BASIC ELECTRONICS & NETWORK THEORY**

Time Allowed: Three hours

Maximum Marks: 80

Minimum Pass Marks: 28

Note: All questions are compulsory and carry equal marks. Part (a) is compulsory from each question and attempt any two parts from (b), (c) and (d).

## udt mines den gester Unit-I

- 1. (a) What are the different passive & active circuit elements?
  - (b) Explain superposition theorem with example.

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| (c) Determine Thevenin's equivalent circuit for the given                |   |  |  |  |
|--|---|--|--|--|
| network.   | 7 |  |  |  |
| S POS REL  |   |  |  |  |
| (d) Explain Thevenin's theorem with example.                             | 7 |  |  |  |
| Unit-II  |   |  |  |  |
| 2. (a) What is an Ideal Diode?   | 2 |  |  |  |
| (b) Explain the working of full-wave rectifier and find expression for : | 7 |  |  |  |
| (i) Transformer utilization factor                                       |   |  |  |  |
| (ii) Efficiency  |   |  |  |  |
| (c) Write down the diode equation and explain the                        |   |  |  |  |
| temperature dependence of diode characteristics.                         | 7 |  |  |  |
| Or   |   |  |  |  |
| Explain the forward & reverse characteristics of PN junction diode.      |   |  |  |  |

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|    | (d) | Prove that zener diode act as voltage regulator and   |   |
|----|-----|---|---|
|    |     | draw the VI characteristics of zener diode.   | - |
|    |     | Unit-III  |   |
| 3. | (a) | What do you mean by reach through/base width modulation?  | 2 |
|    | (b) | Draw and explain characteristics of common-emitter configuration of transistor.   | ĺ |
|    | (c) | Draw the Ebers-Moll model of transistor and explain it.   | Ţ |
|    | (d) | What do you mean by maximum voltage rating of transistor?   | ĺ |
|    |     | Unit-IV   |   |
| 4. | (a) | Why it is required to bias transistor?  | 2 |
|    | (b) | Explain collector to box bias circuit and find expression for stability factor (s).   | ĺ |
|    | (c) | Explain the factors which affect the collector current and responsible for shifting of operating point with respect to temperature. | ĺ |

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(d) Prove that "The transistor act as switch".

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#### Unit-V

5. (a) Give the comparison of JFET over BJT.

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(b) What is JFET? Explain the drain and transfer characteristics of JFET [N-type].

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(c) Explain the working of depletion type MOSFET with characteristics.

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(d) Prove that:

$$g_m = g_{m_0} \left( 1 - \frac{V_{GS}}{V_P} \right)$$

where  $g_{m_0} = \frac{-2I_{DSS}}{V_p}$ .

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Transition to